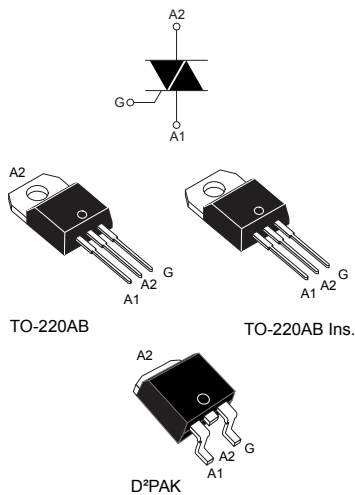


## 12 A Snubberless™, logic level and standard Triacs



### Features

- Medium current Triac
- Low thermal resistance with clip bonding
- Low thermal resistance insulation ceramic for insulated BTA
- High commutation (4Q) or very high commutation (3Q) capability
- BTA series UL1557 certified (file ref: 81734)
- Packages are RoHS (2011/65/EU) compliant

### Description

Available either in through-hole or surface mount packages, the BTA12, BTB12 and T12xx Triac series are suitable for general purpose mains power AC switching. They can be used as ON/OFF function in applications such as static relays, heating regulation or induction motor starting circuit. They are also recommended for phase control operations in light dimmers and appliance motors speed controllers.

The Snubberless™ versions (W suffix and T12xx) are especially recommended for use on inductive loads, because of their high commutation performance. By using an internal ceramic pad, the Snubberless™ series provide an insulated tab (rated at 2500 V<sub>RMS</sub>) complying with UL standards (file reference: E81734).

Logic Level BTA12-600TW and BTA12-600SW offer low holding current, ideal to design light dimmers for LED lamps.

#### Product status link

[BTA12](#)

[BTB12](#)

[T1205](#)

[T1210](#)

[T1235](#)

[T1250](#)

#### Product summary

$I_{T(RMS)}$	12 A
$V_{DRM}/V_{RRM}$	600 and 800 V
$I_{GT(Snubberless)}$	5 / 10 / 35 / 50 mA
$I_{GT(standard)}$	25 / 50

# 1 Characteristics

**Table 1. Absolute maximum ratings ( $T_j = 25\text{ °C}$  unless otherwise stated)**

Symbol	Parameter			Value	Unit
$I_{T(RMS)}$	RMS on-state current (full sine wave)	TO-220AB, D <sup>2</sup> PAK	$T_c = 105\text{ °C}$	12	A
		TO-220AB Ins.	$T_c = 90\text{ °C}$		
$I_{TSM}$	Non repetitive surge peak on-state current (full cycle, $T_j$ initial = $25\text{ °C}$ )	f = 50 Hz	t = 20 ms	120	A
		f = 60 Hz	$t_p = 16.7\text{ ms}$	126	
$I^2t$	$I^2t$ value for fusing		$t_p = 10\text{ ms}$	78	A <sup>2</sup> s
dI/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$ , $tr \leq 100\text{ ns}$	f = 120 Hz	$T_j = 125\text{ °C}$	50	A/ $\mu$ s
$V_{DSM}/V_{RSM}$	Non repetitive surge peak off-state voltage	$t_p = 10\text{ ms}$	$T_j = 25\text{ °C}$	$V_{DRM} / V_{RRM}^+$ 100	V
$I_{GM}$	Peak gate current	$t_p = 20\text{ }\mu$ s	$T_j = 125\text{ °C}$	4	A
$P_{G(AV)}$	Average gate power dissipation		$T_j = 125\text{ °C}$	1	W
$T_{stg}$	Storage junction temperature range			-40 to +150	°C
$T_j$	Operating junction temperature range			-40 to +125	°C

**Table 2. Electrical characteristics ( $T_j = 25\text{ °C}$ , unless otherwise specified) - Snubberless™ and logic level (3 quadrants)**

Symbol	Parameter	Quadrant		T1205	T1210	T1235	T1250	Unit
				BTB12-TW BTA12-TW	BTB12-SW BTA12-SW	BTB12-CW BTA12-CW	BTB12-BW BTA12-BW	
$I_{GT}^{(1)}$	$V_D = 12\text{ V}$ , $R_L = 30\text{ }\Omega$	I - II - III	Max.	5	10	35	50	mA
$V_{GT}$		I - II - III	Max.	1.3				V
$V_{GD}$	$V_D = V_{DRM}$ , $R_L = 3.3\text{ k}\Omega$ , $T_j = 125\text{ °C}$	I - II - III	Min.	0.2				V
$I_H^{(2)}$	$I_T = 100\text{ mA}$	I - II - III	Max.	10	15	35	50	mA
$I_L^{(2)}$	$I_G = 1.2 \times I_{GT}$	I - III	Max.	10	25	50	70	mA
		II	Max.	15	30	60	80	
$dV/dt^{(2)}$	$V_D = 67\% V_{DRM}$ , gate open, $T_j = 125\text{ °C}$		Max.	20	40	500	1000	V/ $\mu$ s
$(dI/dt)_c^{(2)}$	$(dV/dt)_c = 0.1\text{ V}/\mu$ s, $T_j = 125\text{ °C}$		Min.	3.5	6.5			A/ms
	$(dV/dt)_c = 10\text{ V}/\mu$ s, $T_j = 125\text{ °C}$		Min.	1.0	2.9			
	Without snubber, $T_j = 125\text{ °C}$		Min.			6.5	12	

1. Minimum  $I_{GT}$  is guaranteed at 5 % of  $I_{GT}$  max.
2. For both polarities of A2 referenced to A1

**Table 3. Electrical characteristics ( $T_j = 25\text{ }^\circ\text{C}$ , unless otherwise specified) - Standard Triac (4 quadrants)**

Symbol	Parameter	Quadrant		Value		Unit
				C	B	
$I_{GT}^{(1)}$	$V_D = 12\text{ V}$ , $R_L = 30\ \Omega$	I - II - III	Max.	25	50	mA
		IV		50	100	
$V_{GT}$		All	Max.	1.3		V
$V_{GD}$	$V_D = V_{DRM}$ , $R_L = 33\text{ k}\Omega$ , $T_j = 125\text{ }^\circ\text{C}$	All	Min.	0.2		V
$I_H^{(2)}$	$I_T = 500\text{ mA}$	I - II - III	Max.	25	50	mA
$I_L$	$I_G = 1.2\ I_{GT}$	I - III - IV	Max.	40	50	mA
		II		80	100	
$dV/dt^{(2)}$	$V_D = 67\%$ $V_{DRM}$ gate open, $T_j = 125\text{ }^\circ\text{C}$		Min.	200	400	V/ $\mu\text{s}$
$(dV/dt)_C^{(2)}$	$(dI/dt)_C = 5.3\text{ A/ms}$ , $T_j = 125\text{ }^\circ\text{C}$		Min.	5	10	V/ $\mu\text{s}$

1. Minimum  $I_{GT}$  is guaranteed at 5 % of  $I_{GT}$  max.
2. For both polarities of A2 referenced to A1

**Table 4. Static electrical characteristics**

Symbol	Test conditions			Value	Unit
$V_{TM}^{(1)}$	$I_{TM} = 17\text{ A}$ , $t_p = 380\ \mu\text{s}$	$T_j = 25\text{ }^\circ\text{C}$	Max.	1.55	V
$V_{TO}^{(1)}$	threshold on-state voltage	$T_j = 125\text{ }^\circ\text{C}$	Max.	0.85	V
$R_D^{(1)}$	Dynamic resistance	$T_j = 125\text{ }^\circ\text{C}$	Max.	35	m $\Omega$
$I_{DRM}$ $I_{RRM}$	$V_{DRM} = V_{RRM}$	$T_j = 25\text{ }^\circ\text{C}$	Max.	5	$\mu\text{A}$
		$T_j = 125\text{ }^\circ\text{C}$	Max.	1	mA

1. For both polarities of A2 referenced to A1

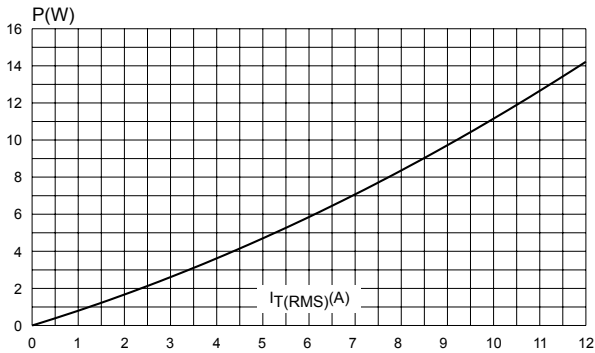
**Table 5. Thermal resistance**

Symbol	Parameter			Value	Unit	
$R_{th(j-c)}$	Max. junction to case thermal resistance (AC)		D <sup>2</sup> PAK / TO-220AB	Max.	1.4	$^\circ\text{C/W}$
			TO-220AB insulated	Max.	2.3	
$R_{th(j-a)}$	Junction to ambient	$S = 2\text{ cm}^2$ <sup>(1)</sup>	D <sup>2</sup> PAK	Typ.	45	$^\circ\text{C/W}$
	Junction to ambient		TO-220AB / TO-220AB insulated	Typ.	60	

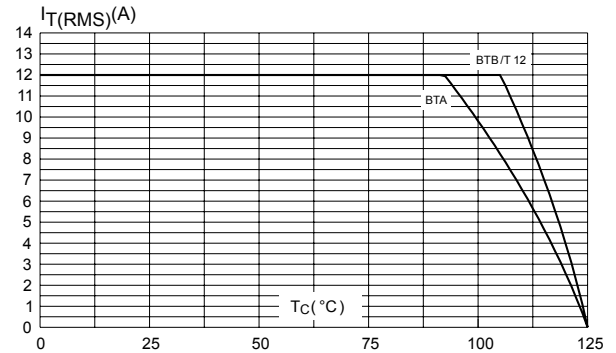
1.  $S$  = Copper surface under tab.

### 1.1 Characteristics (curves)

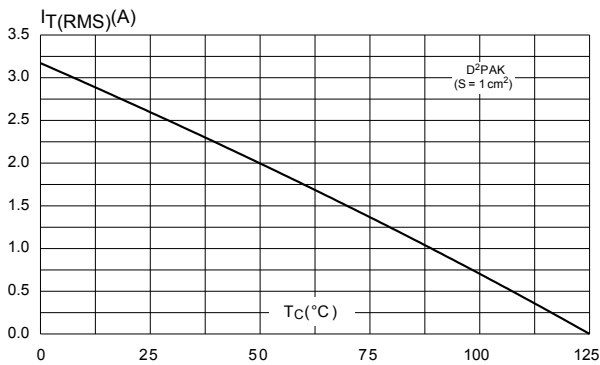
**Figure 1. Maximum power dissipation versus on-state RMS current (full cycle)**



**Figure 2. RMS on-state current cycle versus case temperature (full cycle)**



**Figure 3. RMS on-state current versus ambient temperature (printed circuit board FR4, copper thickness: 35  $\mu\text{m}$ ) (full cycle)**



**Figure 4. Relative variation of thermal impedance versus pulse duration**

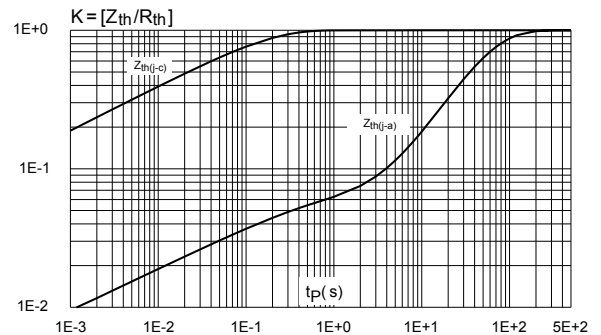


Figure 5. On-state characteristics (maximum values)

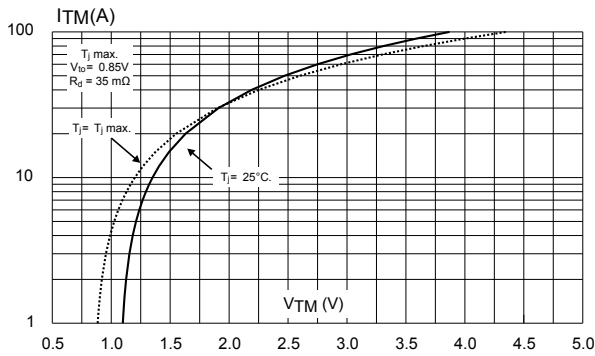


Figure 6. Surge peak on-state current versus number of cycles

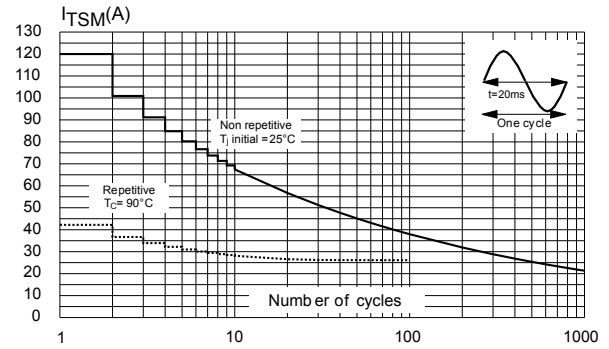


Figure 7. Non repetitive surge peak on-state current for a sinusoidal pulse

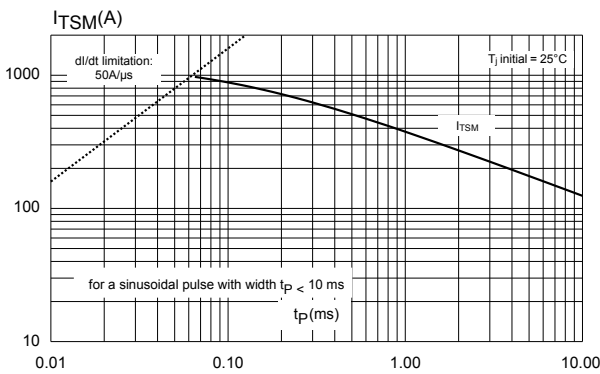
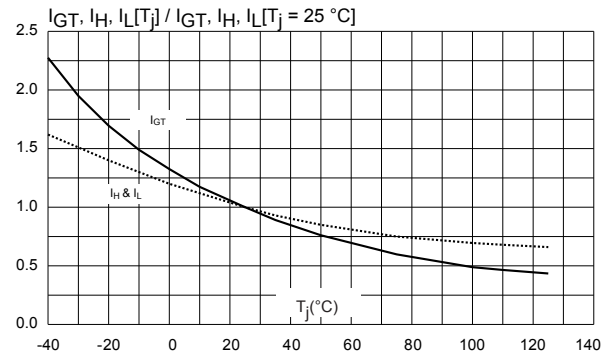
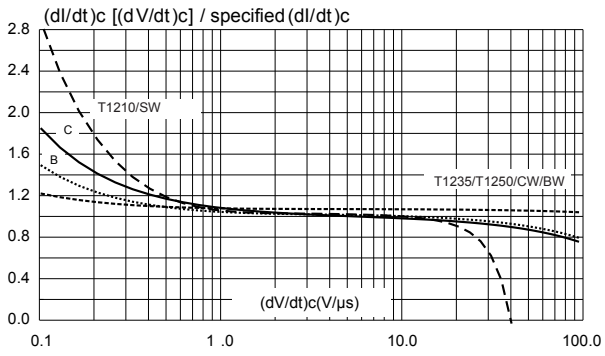


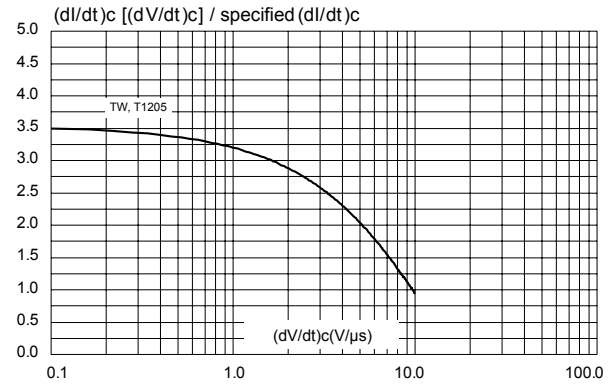
Figure 8. Relative variation of gate trigger current holding current and latching current versus junction temperature (typical values)



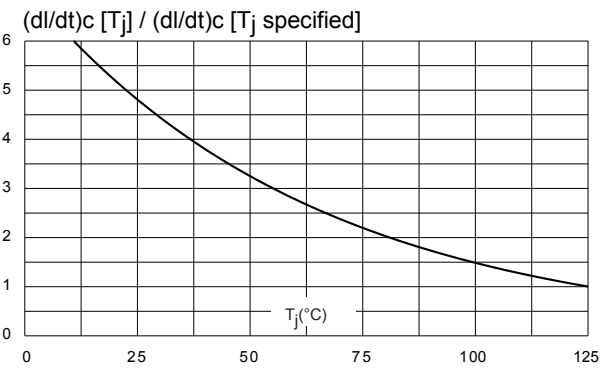
**Figure 9. Relative variation of critical rate of decrease of main current versus (dV/dt)<sub>c</sub> (typical values)**



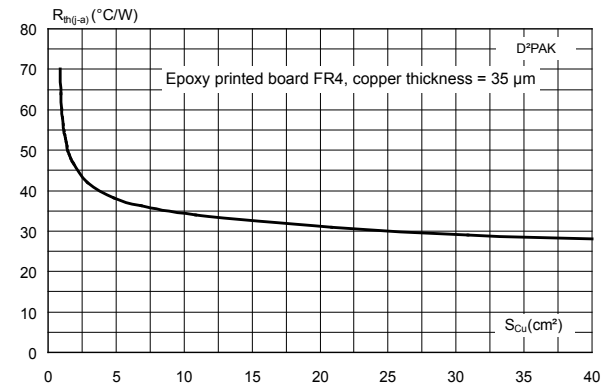
**Figure 10. Relative variation of critical rate of decrease of main current versus (dV/dt)<sub>c</sub> (typical values)(TW)**



**Figure 11. Relative variation of critical rate of decrease of main current versus junction temperature**



**Figure 12. D<sup>2</sup>PAK thermal resistance junction to ambient versus copper surface under tab**



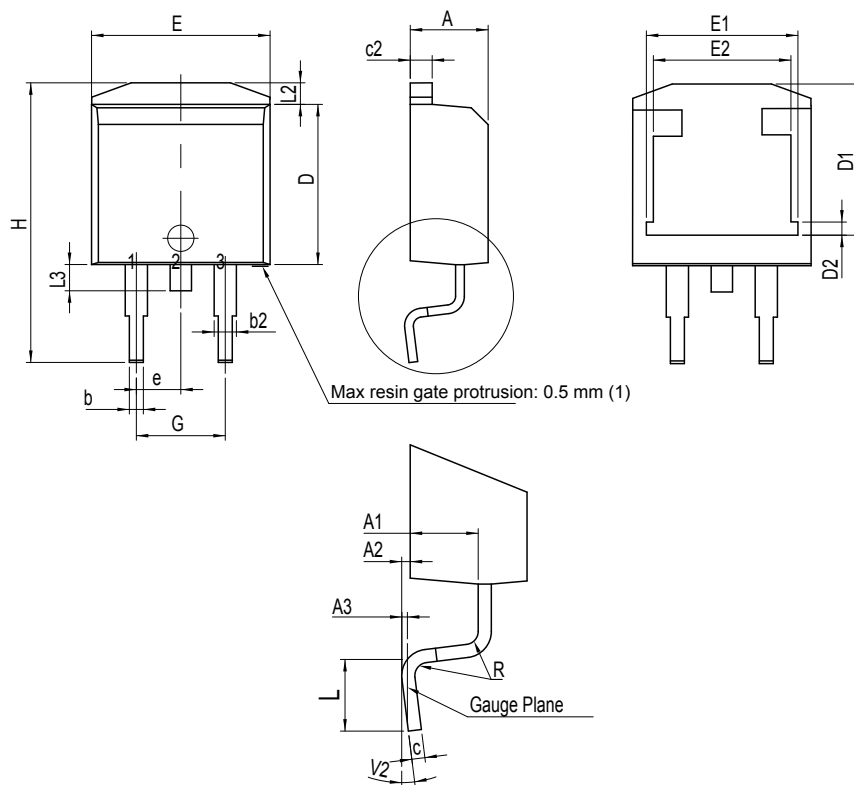
## 2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of **ECOPACK®** packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK® is an ST trademark.

### 2.1 D<sup>2</sup>PAK package information

- ECOPACK2® compliant
- Lead-free package leads finishing
- Molding compound resin is halogen-free and meets UL standard level V0

Figure 13. D<sup>2</sup>PAK package outline



(1) Resin gate is accepted in each of position shown on the drawing, or their symmetrical.

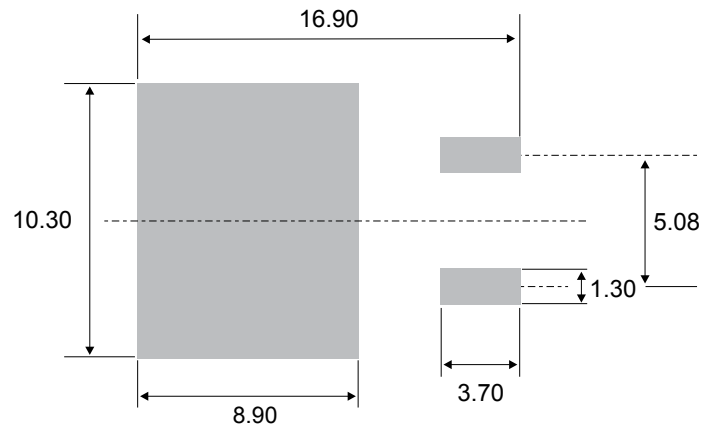
**Table 6. D<sup>2</sup>PAK package mechanical data**

Ref.	Dimensions					
	Millimeters			Inches <sup>(1)</sup>		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.30		4.60	0.1693		0.1811
A1	2.49		2.69	0.0980		0.1059
A2	0.03		0.23	0.0012		0.0091
A3		0.25			0.0098	
b	0.70		0.93	0.0276		0.0366
b2	1.25		1.7	0.0492		0.0669
c	0.45		0.60	0.0177		0.0236
c2	1.21		1.36	0.0476		0.0535
D	8.95		9.35	0.3524		0.3681
D1	7.50		8.00	0.2953		0.3150
D2	1.30		1.70	0.0512		0.0669
e	2.54			0.1		
E	10.00		10.28	0.3937		0.4047
E1	8.30		8.70	0.3268		0.3425
E2	6.85		7.25	0.2697		0.2854
G	4.88		5.28	0.1921		0.2079
H	15		15.85	0.5906		0.6240
L	1.78		2.28	0.0701		0.0898
L2	1.27		1.40	0.0500		0.0551
L3	1.40		1.75	0.0551		0.0689
R		0.40			0.0157	
V2	0°		8°	0°		8°

1. Dimensions in inches are given for reference only



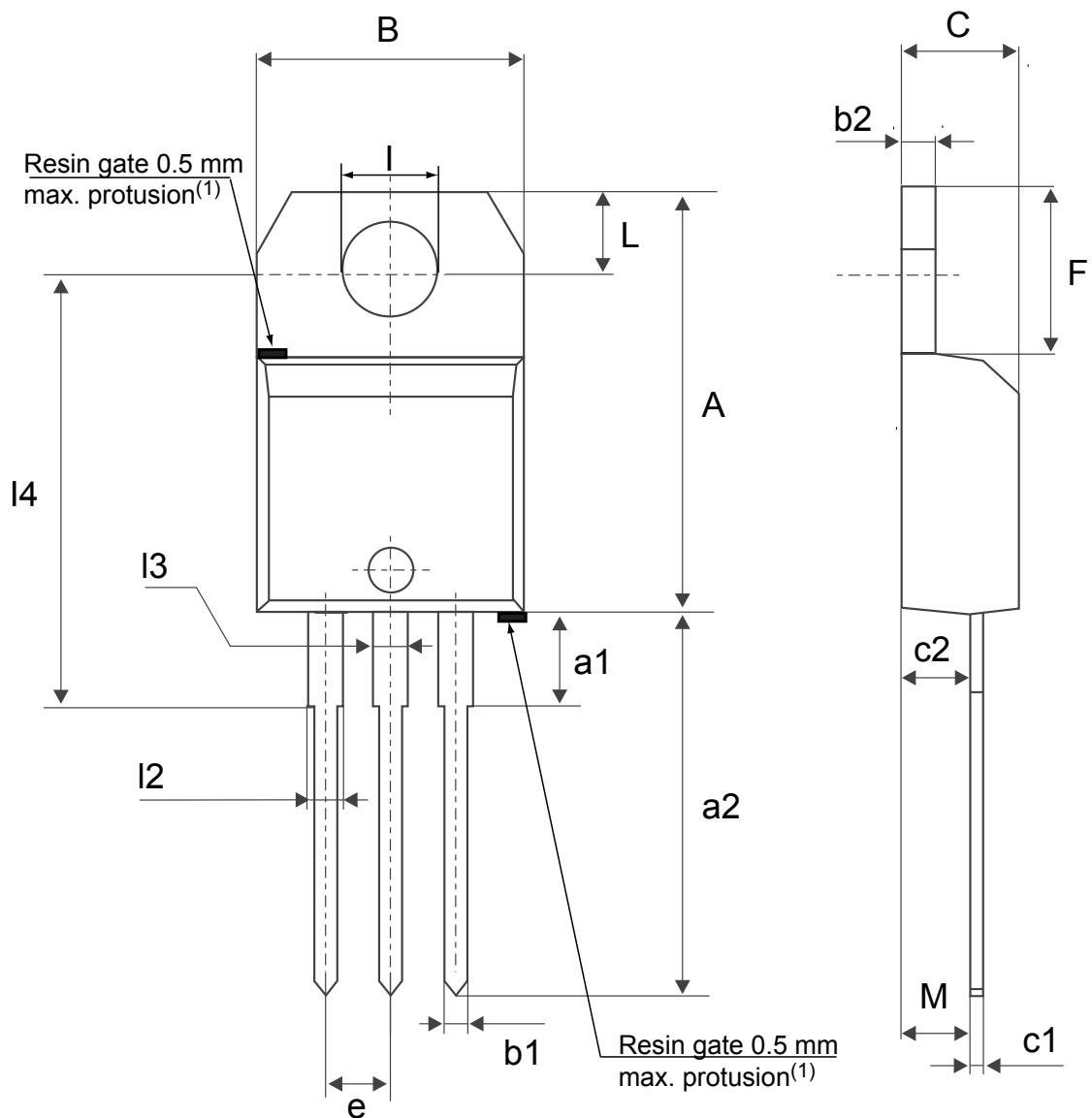
Figure 14. D<sup>2</sup>PAK recommended footprint (dimensions are in mm)



## 2.2 TO-220AB insulated package information

- Epoxy meets UL 94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.55 N·m
- Maximum torque value: 0.70 N·m

**Figure 15. TO-220AB insulated and non insulated package outline**



(1) Resin gate position accepted in one of the two positions or in the symmetrical opposites.

**Table 7. TO-220AB insulated and non insulated package mechanical data**

Ref.	Dimensions					
	Millimeters			Inches <sup>(1)</sup>		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.20		15.90	0.5984		0.6260
a1		3.75			0.1476	
a2	13.00		14.00	0.5118		0.5512
B	10.00		10.40	0.3937		0.4094
b1	0.61		0.88	0.0240		0.0346
b2	1.23		1.32	0.0484		0.0520
C	4.40		4.60	0.1732		0.1811
c1	0.49		0.70	0.0193		0.0276
c2	2.40		2.72	0.0945		0.1071
e	2.40		2.70	0.0945		0.1063
F	6.20		6.60	0.2441		0.2598
l	3.73		3.88	0.1469		0.1528
L	2.65		2.95	0.1043		0.1161
l2	1.14		1.70	0.0449		0.0669
l3	1.14		1.70	0.0449		0.0669
l4	15.80	16.40	16.80	0.6220	0.6457	0.6614
M		2.6			0.1024	

1. Inch dimensions are for reference only.

### 3 Ordering information

Figure 16. Ordering information scheme (BTA12 and BTB12 series)

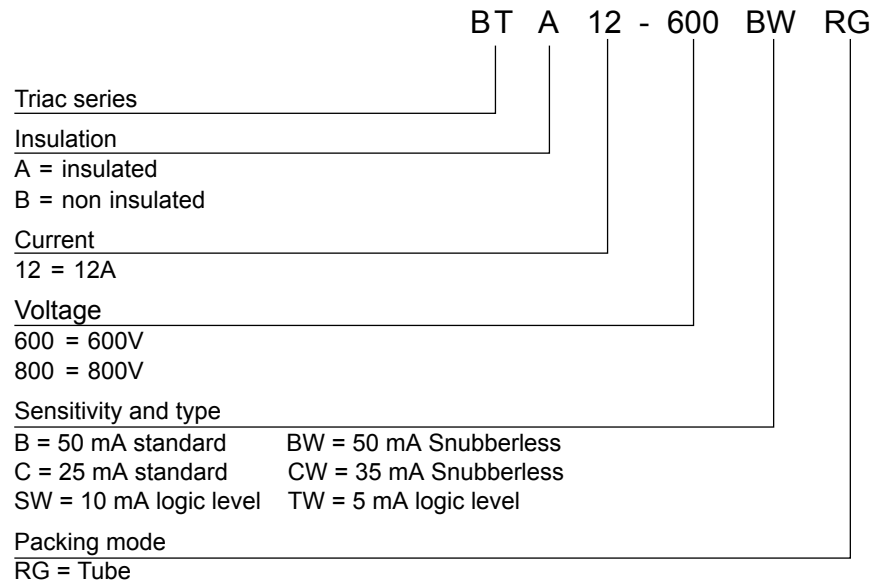
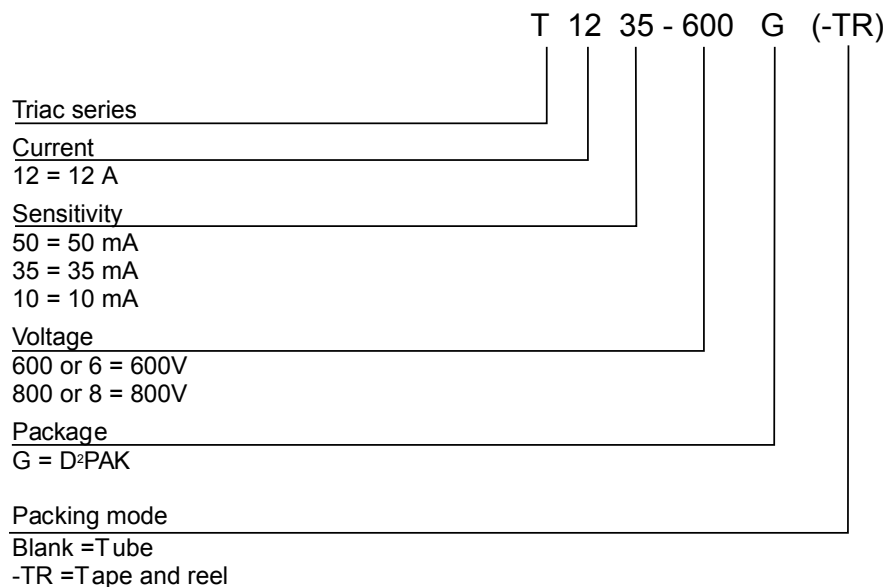


Figure 17. Ordering information scheme (T12 series)



**Table 8. Product selector**

Part number	Voltage (xxx)		Sensitivity	Type	Package
	600	800			
BTB12-600C	X		25 mA	Standard	TO-220AB
BTB12-600B	X		50 mA	Standard	TO-220AB
BTB12-600TW	X		5 mA	Snubberless™	TO-220AB
BTB12-600SW	X		10 mA	Snubberless™	TO-220AB
BTB12-xxxCW	X	X	35 mA	Snubberless™	TO-220AB
BTB12-600BW	X		50 mA	Snubberless™	TO-220AB
BTA12-600C	X		25 mA	Standard	TO-220AB Ins.
BTA12-xxxB	X	X	50 mA	Standard	TO-220AB Ins.
BTA12-600TW	X		5 mA	Snubberless™	TO-220AB Ins.
BTA12-xxxSW	X	X	10 mA	Snubberless™	TO-220AB Ins.
BTA12-xxxCW	X	X	35 mA	Snubberless™	TO-220AB Ins.
BTA12-xxxBW	X	X	50 mA	Snubberless™	TO-220AB Ins.
T1205-600G	X		5 mA	Snubberless™	D <sup>2</sup> PAK
T1210-6G	X		10 mA	Snubberless™	D <sup>2</sup> PAK
T1210-800G		X	10 mA	Snubberless™	D <sup>2</sup> PAK
T1235-xxxG	X	X	35 mA	Snubberless™	D <sup>2</sup> PAK
T1250-600G	X		50 mA	Snubberless™	D <sup>2</sup> PAK

**Table 9. Ordering information**

Order code	Marking	Package	Weight	Base qty.	Delivery mode
BTA12-600BRG	BTA12-600B	TO-220AB Ins.	1.9 g	50	Tube
BTA12-600BWRG	BTA12-600BW				
BTA12-600CRG	BTA12-600C				
BTA12-600CWRG	BTA12-600CW				
BTA12-600SWRG	BTA12-600SW				
BTA12-600TWRG	BTA12-600TW				
BTA12-800BRG	BTA12-800B				
BTA12-800BWRG	BTA12-800BW				
BTA12-800CWRG	BTA12-800CW				
BTA12-800SWRG	BTA12-800SW				
BTB12-600BRG	BTB12-600B	TO-220AB			
BTB12-600BWRG	BTB12-600BW				
BTB12-600CRG	BTB12-600C				
BTB12-600CWRG	BTB12-600CW				
BTB12-600SWRG	BTB12-600SW				
BTB12-600TWRG	BTB12-600TW				
BTB12-800CWRG	BTB12-800CW				
T1205-600G-TR	T1205-600G	D <sup>2</sup> PAK	1.38 g	1000	Tape and reel 13"
T1210-6G-TR	T1210-6G				
T1210-800G-TR	T1210-800G				
T1235-600G-TR	T1235-600G				
T1235-800G-TR	T1235-800G				
T1250-600G-TR	T1250-600G				
T1210-6G	T1210-6G			50	Tube
T1235-600G	T1235-600G				

**Table 10. Document revision history**

Date	Revision	Changes
Sep-2002	6A	Last update.
15-Mar-2005	7	1. I2PAK package added. 2. TO-220AB delivery mode changed from bulk to tube.
27-May-2005	8	T1210 added.
28-Sep-2007	9	Reformatted to current standards. T1250 added.
02-Feb-2017	10	Removed I <sup>2</sup> PAK package. Updated Figure 7: "Non-repetitive surge peak on-state current" and Table 9: "Product selector" and Table 10: "Ordering information".
9-Aug-2018	11	Updated D <sup>2</sup> PAK package information and <a href="#">Figure 10</a> . Updated <a href="#">Section Product status / summary</a> .
07-Feb-2019	12	Updated links syntax.

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